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Electrospinning preparation of p-type NiO/n-type CeO₂ heterojunctions with enhanced photocatalytic activity

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ABSTRACT

Novel p-type NiO/n-type CeO₂ heterojunctions, with cubic NiO particles embedded on the CeO₂ nanofibers, were successfully prepared by the electrospinning technique. The photocatalytic activity for MB degradation under UV light irradiation of the NiO/CeO₂ heterojunction is much higher than that of pure NiO or CeO₂. The rate constant of MB degradation by NiO/CeO₂ is about 4 times and 2 times than those of pure NiO and CeO₂ under UV light irradiation, respectively. The excellent photocatalytic activity of the NiO/CeO₂ heterostructures is closely related to the fast transfer and efficient separation of electron–hole pairs between NiO and CeO₂ due to the formation of the heterojunction and their matching band positions.

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1. Introduction

Semiconductor photocatalysis is regarded as a promising avenue toward solving the worldwide energy shortage and environment pollution with abundant solar light [1,2]. Of the well-known photocatalysts, cerium dioxide (CeO₂), naturally n-type semiconductors with a wide bandgap ($E_g=3.2$ eV), has been deemed as one of the most promising photocatalysts for the degradation of organic pollutants and water splitting for hydrogen generation owing to its high incident photon-to-electron conversion efficiencies, low cost, remarkable chemical stabilities along with safety advantage [3,4]. Nevertheless, the photocatalytic activity of CeO₂ system is largely limited by the quick recombination of the photoinduced electrons and holes [5]. To overcome this bottleneck, an effective strategy is the coupling of two semiconductors, CeO₂ and another semiconductor with the matching band positions, to form heterojunctions to increase the separation efficiency of photogenerated electron–hole pairs of CeO₂ photocatalysts [6,7]. So far, various CeO₂-based heterojunctions, such as Ag₃PO₄-CeO₂ [5], ZnO-CeO₂ [8] and BiVO₄-CeO₂ [9], have been investigated to suppress the recombination of photogenerated electron–hole pairs by the mutual transfer of photogenerated electrons or holes in the heterojunctions [10–12]. It is known that nickel oxide (NiO), a p-type semiconductor ($E_g=3.5$ eV) with high hole mobility and low lattice mismatch with CeO₂, is conducive to

the fabrication of p–n heterojunction with CeO₂ [13,14]. Theoretically, the formed p–n heterojunction could provide a potential driving force and facilitate the transfer of electron–hole pairs the owing to the building of the internal electric field, with its field direction from the n-type CeO₂ to the p-type NiO [14–17]. Thus, it is significant to synthesize p-type NiO/n-type CeO₂ heterojunction, which might facilitate the easier transfer and efficient separation of photogenerated electron–hole pairs and improve the photocatalytic efficiency.

Herein, novel p-type NiO/n-type CeO₂ heterostructures were successfully prepared by the electrospinning technique. It is interesting that the cubic NiO nanoparticles are uniformly embedded in the CeO₂ nanofibers and form a heterostructure. Moreover, the synthesized NiO/CeO₂ heterojunction photocatalyst displays much higher activity than that of single NiO or CeO₂ under the irradiation of UV light. To the best of our knowledge, this is the first report on the electrospinning preparation of NiO/CeO₂ heterojunction photocatalyst.

2. Experimental section

The p-type NiO/n-type CeO₂ heterojunctions were synthesized using an electrospinning and calcination method. In a typical procedure, 0.0005 mol Ni(CH₃COO)₂ and 0.0005 mol CeCl₃ were mixed with 2.2 g ethanol and 2.2 g *N,N*-dimethylformamide (DMF) under vigorous stirring for 30 min. Subsequently, 0.38 g of poly(vinyl pyrrolidone) (PVP, $M_w=300,000$) was added to the above solution. After stirring for 12 h, the precursor solution was transferred to a syringe for electrospinning. The positive terminal of a

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variable highvoltage power supply was connected to the needle tip of the syringe while the other terminal was connected to the collector plate. In a typical electrospinning process, the precursor solution was electrospun at 20 kV voltage, 20 cm working distance, and 0.4 mL/h flow rate at room temperature. The as-spun samples were calcined at 500 °C for 3 h in air to obtain NiO/CeO₂ heterojunctions with original Ni/Ce molar ratios of 1. For comparison, pure CeO₂ and NiO were also prepared using similar experimental conditions.

The crystal structure of the samples was characterized by a power X-ray diffraction (XRD, Siemens D-5000 diffractometer with Cu K α irradiation) and high-resolution transmission electron microscopy (HRTEM, JEOL JSM-2010F). The morphological details of the prepared samples were investigated by field emission scanning electron microscopy (FESEM, S-4800) and transmission electron microscopy (TEM, JEOL JEM 2010F). The Brunauer–Emmett–Teller (BET) specific surface area of the samples was analyzed by nitrogen adsorption in a Micromeritics ASAP 2020 nitrogen adsorption apparatus.

The photocatalytic performance for the degradation of methylene blue (MB, 10 mg/L, 80 mL) with 30 mg photocatalysts (CeO₂, NiO or NiO/CeO₂) under UV light was explored. A 300 W UV lamp was chosen as the UV light source. Prior to irradiation, solutions suspended with photocatalysts were sonicated in the dark for 10 min to ensure the adsorption–desorption equilibrium of MB on the surface of the photocatalysts. During irradiation, the samples were withdrawn at regular time intervals and centrifuged to remove the catalysts. The photodegradation efficiency was monitored by measuring the absorbance of the solution samples at its characteristic absorption wavelength of 663 nm (MB) with a UV–Vis spectrophotometer at room temperature.

3. Results and discussion

The typical SEM images of pure CeO₂, NiO and the NiO/CeO₂ heterojunction are shown in Fig. 1. It can be seen that the as-spun CeO₂ nanofibers (Fig. 1a), with diameters of ~110 nm, possess smooth and uniform surfaces, whereas the NiO nanofibers (Fig. 1b), with diameter ranging from 50 to 100 nm, are rough and consist of smaller nanoparticles. The SEM image in Fig. 1c and the TEM micrograph shown in the inset of Fig. 1c reveal that the NiO/CeO₂ heterojunction is composed of two distinct phases. The cubic-shaped particles are NiO. It is noticeable that the NiO nanoparticles are uniformly embedded in the CeO₂ nanofibers and form a heterostructure. To further confirm the crystallographic structure of the NiO/CeO₂ heterojunction, HRTEM measurement was carried out. The HRTEM images of NiO/CeO₂ heterojunction in Fig. 1d show two distinct sets of lattice fringes. The uniform lattice fringes have spacings corresponding to the (1 1 1) plane of cubic fluorite-type CeO₂ and the (1 1 1) plane of cubic NiO, respectively.

The XRD patterns of all the samples are shown in Fig. 2. It is observed that all of the diffraction peaks of pure CeO₂ correspond to the cubic fluorite-type CeO₂ structure (JCPDS no. 81-0792), while those of NiO can be indexed to the body-centered cubic structure of NiO (JCPDS no. 78-0643). As expected, the XRD pattern of the NiO/CeO₂ composite shows the mixed patterns of CeO₂ and NiO, and excludes the possibility of any third phase formation, indicating that the NiO/CeO₂ heterojunction has been successfully prepared.

The photocatalytic activity of these samples was evaluated by photodegradation of MB. The degradation efficiency of MB over pure CeO₂, NiO and the NiO/CeO₂ heterojunction photocatalyst, or without the photocatalyst, under UV light irradiation is presented

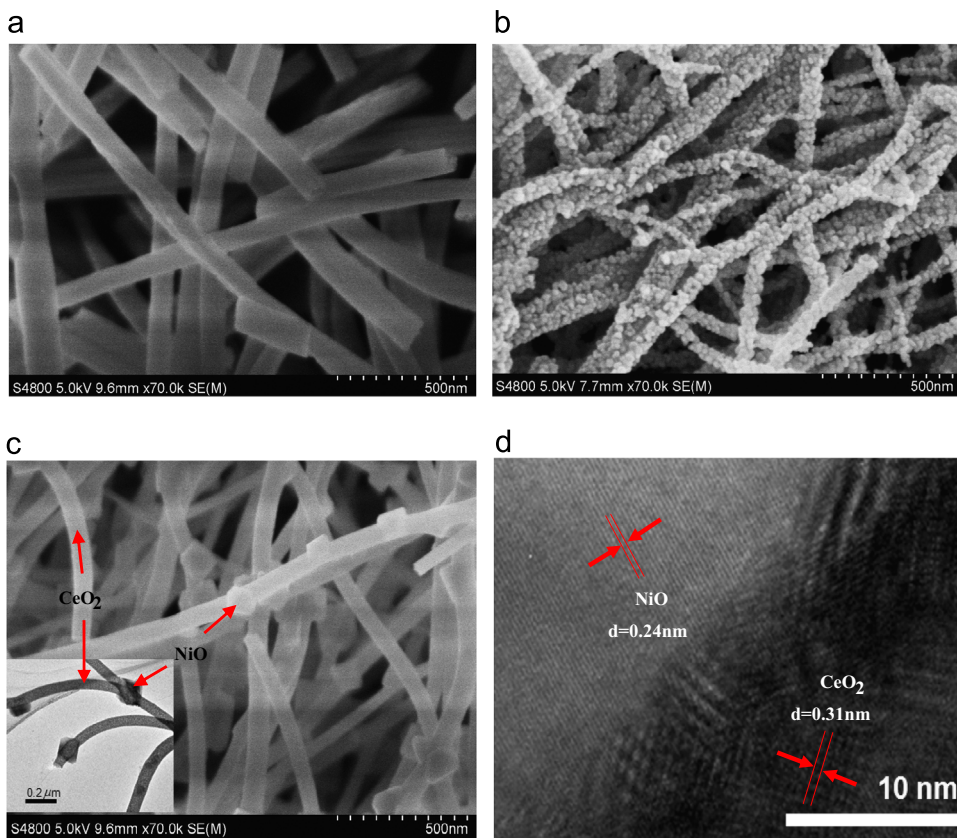


Fig. 1. SEM images of (a) CeO₂, (b) NiO, (c) NiO/CeO₂ heterojunction, and (d) HRTEM image of the NiO/CeO₂ heterojunction.

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